Lead (Pb) Free Product RoHS compliant

SMC750

High Performance infrared SMD LED on ceramics

SMC750 consists of an AlGaAs LED mounted on the ceramics package and is sealed with silicone or epoxy resin.

It emits a spectral band of radiation at 750nm.

◆ Specifications

1) Product Name SMD type infrared LED

2) Type No. SMC750

3) Chip

(1) Chip Material AlGaAs(2) Peak Wavelength 750nm typ.

4) Package

(1) Package Ceramics

(2) Lens Silicone or Epoxy resin

◆Absolute Maximum Ratings

anode mark	silicone resin
	2±0.2
1.1±0.15	2±0.2 - 5 3±0.2 - 9
anode	cathode
	-0.5 0.5

Item	Symbol	Maximum Rated Value	Unit	Ambient Temperature	
Power Dissipation	PD	190	mW	Ta=25°C	
Forward Current	lF	100	mA	Ta=25°C	
Pulse Forward Current	IFP	500	mA	Ta=25°C	
Reverse Voltage	VR	5	V	Ta=25°C	
Operating Temperature	Topr	-20 ~ +80	°C		
Storage Temperature	Тѕтс	-30 ~ +80	°C		
Soldering Temperature	TsoL	240	°C		

‡Pulse Forward Current condition: Duty=1% and Pulse Width=10us.

‡Soldering condition: Soldering condition must be completed within 3 seconds at 240°C

◆ Electro-Optical Characteristics [Ta=25°C]

Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	VF	Ir=50mA		1.75	1.95	V
Reverse Current	lr	VR=5V			10	uA
Total Radiated Power	Po	I=50mA	5.0	10.0		mW
Radiant Intensity	ΙE	I=50mA	2.0	5.0		mW/sr
Peak Wavelength	λP	I=50mA		750		nm
Half Width	Δλ	I=50mA		30		nm
Viewing Half Angle	θ 1/2	I=50mA		±55		deg.
Rise Time	tr	I=50mA		80		ns
Fall Time	tf	I=50mA		80		ns

‡Total Radiated Power is measured by Photodyne #500

‡Radiant Intensity is measured by Tektronix J-6512.